ANSI C63.19-2001 Revision Draft 3.12

FCC HAC TEST REPORT

For

Smart Phone

Trade Name: N/A

Model: LIBR100

Issued to

High Tech Computer Corp. 1F, No. 6-3, Baoqiang Rd., Xindian City, Taipei County 231, Taiwan, R.O.C.

Issued by

Compliance Certification Services Inc. No. 11, Wu-Kung 6 Rd, Wu-Ku Hsiang, Wu-Ku Industrial District, Taipei Hsien, (248) Taiwan. http://www.ccsemc.com.tw service@tw.ccsemc.com



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1. HEARING AID COMPATIBILITY CERTIFICATE

APPLICATION TYPE:	Original Grant
FCC RULE PART(s):	47 CFR PART §20.19(b)
APPLICANT:	High Tech Computer Corp.
ADDRESS:	1F, No. 6-3, Baoqiang Rd., Xindian City, Taipei County 231, Taiwan, R.O.C.
TRADE NAME:	N/A
MODEL:	LIBR100
TEST SAMPLE TYPE:	Dual Band CDMA PDA Phone with Bluetooth
Date of Test:	March 26, 2007

APPLICABLE STANDARDS				
STANDARD	TEST RESULT			
ANSI C63.19 – 2001 Revision Draft 3.12	No non-compliance noted			
HAC RATE CATEGORY				
M3 (RF EMISSION)				

The device was tested by Compliance Certification Services Inc. in accordance with the measurement methods and procedures specified in ANSI C63.19. The test results in this report apply only to the tested sample of the stated device/equipment. Other similar device/equipment will not necessarily produce the same results due to production tolerance and measurement uncertainties.

Approved by:

Johnny Rin

Johnny Liu Section Manager Compliance Certification Services Inc.

Reviewed by:

ex. la.

Rex Lai Section Manager Compliance Certification Services Inc.

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2. EQUIPMENT UNDER TEST DESCRIPTION AND TEST SUMMARY

Smart Phone	
Model Number	LIBR100
Model Discrepancy	N/A
Normal operation:	Held to ear for close slide cover and open slide cover mode
Radio modules:	 CDMA: Manufacture by Qualcomm, model number: MSM7500 Bluetooth- Manufacture by Murata, model number: LBMA46LDC2
Duty cycle of Transmitter	100% for CDMA, and bluetooth
Power supply	Rechargeable Li-ion Polymer Battery Simplo Technology Co., Ltd. Model number: LIBR160, 3.7VDC, 1050mAh. (only one type of battery to be used in the EUT)
Accessories	 Splitter: Acon, P/N: CBAUB-617-X Holster with belt clip (Pouch) 1- New Tech, P/N:HTC-326 (belt clip) Holster with belt clip (Pouch) 2- New Tech, P/N:HTC-333 Headset : Merry, P.N: EMC220-008 Mini USB Cable: MEC, P/N: 60-4251-100 Splitter Cable: MEC, P/N: 60-4269-300
Charger	 Trade name: DELTA; model no.: ADP-5FH X Trade name: Tamura; model no.: JHA050100UU05 Trade name: Phihong; model no.: PSAA05X-050
Frequency Range	CDMA Cellular band: 824.7 MHz to 848.31 MHz CDMA PCS band: 1851.25 MHz to1908.85 MHz Bluetooth: 2402MHz to 2480MHz
Transmit Power	CDMA Cellular Band: 25.08 dBm CDMA PCS band: 25.08 dBm Bluetooth: -0.10 dBm
Test Result	CDMA Cellular band: E-Field: 40.09 dB V/m -M4 Phone H-Field: -9.77 dB A/m-M3 Phone CDMA PCS band: E-Field: 38.55 dB V/m-M4 Phone H-Field: -10.04 dB A/m-M3 Phone
Modulation Technique	DSSS, FHSS
Antenna Specification	CDMA (Cellular and PCS band): Monopole antenna Bluetooth: Monopole antenna



3. REQUIREMENTS FOR COMPLIANCE TESTING DEFINED BY THE FCC

In July 2003, the Federal Communications Commission (FCC) modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1988 to require that wireless phone manufacturers and wireless phone service providers make digital wireless phones accessible to individuals who use hearing aids.

Since 2003, more people have come to rely on wireless phones for safety, business, and personal uses. For these reasons, it is vital for individuals with a hearing impairment have access to digital wireless phones. The FCC has taken steps to increase access to wireless telephones by requiring wireless carriers and equipment manufacturers to make more digital wireless phones hearing aid-compatible.

In June 2005, the FCC reaffirmed the timetable for the development and sale of digital wireless phones that are compatible with hearing aids. Specifically, the rules are as follows:

- By **September 16, 2005**, the five largest wireless carriers (Sprint, Nextel, Verizon Wireless, Cingular and T-Mobile) must:
 - either make **four** hearing aid-compatible handset models available for each air interface (an air interface the standard operating system of a wireless network that selects which radio channels are employed during a call) or
 - ensure that 25% of their handset models are hearing compatible.
- By **September 16, 2006**, the five largest wireless carriers must, per air interface, make **five** hearing aid-compatible handset models available for each air interface.
- All wireless carriers must ensure that 50% of their handset models are hearing aid-compatible by February 18, 2008.
- Hearing aid-compatible wireless phones must have prominent exterior labeling indicating the handset's technical rating and have more detailed information included inside the package. This information will allow you to quickly and easily determine which wireless phones are compatible with your hearing aid.
- All carrier owned and operated retail outlets must make live, in-store testing available to consumers. Carriers are encouraged to include hearing aid-compatible information on "call-out cards" as part of the handset display.
- Wireless service providers are encouraged to provide a 30-day trial period or adopt a flexible return policy. This allows individuals with hearing aids sufficient time to choose suitable wireless phones and become comfortable with them.

Note: Wireless carriers, service providers, and handset manufacturers are exempt from these rules if they only offer **two or fewer digital handset models** on a particular air interface.

The FCC also encourages digital wireless phone manufacturers and service providers to offer at least one compliant handset that is a lower-priced model and one that has higher-end features and encourages hearing-aid manufacturers to label their pre-customization products according to the ANSI standard.



4. SYSTEM DESCRIPTION

4.1 MEASUREMENT SYSTEM DIAGRAM

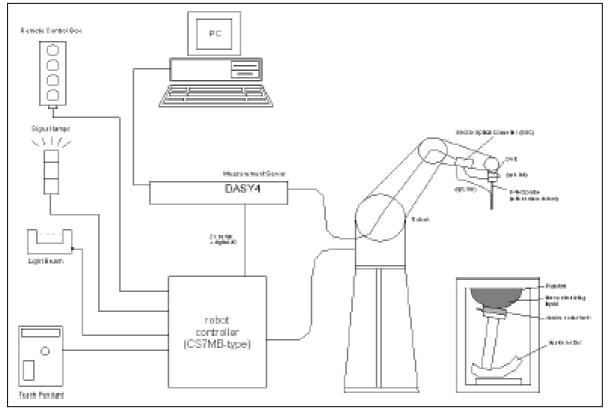


Figure 1: Measurement System diagram

The DASY4 system for performing compliance tests consists of the following items:

- A standard high precision 6-axis robot (St^{*}aubli RX family) with controller, teach pendant and software. An arm extension for accommodating the data acquisition electronics (DAE).
- A dosimetric probe, i.e., an isotropic E-field probe optimized and calibrated for usage in tissue simulating liquid. The probe is equipped with an optical surface detector system.
- A data acquisition electronics (DAE) which performs the signal amplification, signal multiplexing, ADconversion, offset measurements, mechanical surface detection, collision detection, etc. The unit is battery powered with standard or rechargeable batteries. The signal is optically transmitted to the EOC.
- The Electro-optical converter (EOC) performs the conversion between optical and electrical of the signals for the digital communication to the DAE and for the analog signal from the optical surface detection. The EOC is connected to the measurement server.
- The function of the measurement server is to perform the time critical tasks such as signal filtering, control of the robot operation and fast movement interrupts.
- A probe alignment unit which improves the (absolute) accuracy of the probe positioning.
- A computer operating Windows 2000 or Windows XP.
- DASY4 software.
- Remote control with teach pendant and additional circuitry for robot safety such as warning lamps, etc.
- The SAM twin phantom enabling testing left-hand and right-hand usage.
- Validation dipole kits allowing validating the proper functioning of the system.

5. SYSTEM COMPONENTS

5.1 DASY4 MEASUREMENT SERVER



The DASY4 measurement server is based on a PC/104 CPU board with a 166MHz low-power Pentium, 32MB chip disk and 64MB RAM. The necessary circuits for communication with either the DAE3 electronic box as well as the 16-bit AD-converter system for optical detection and digital I/O interface are contained on the DASY4 I/O-board, which is directly connected to the PC/104 bus of the CPU board.

Figure 2:DASY4 Server

The measurement server performs all real-time data evaluation for field measurements and surface detection, controls robot movements and handles safety operation. The PC-operating system cannot interfere with these time critical processes. All connections are supervised by a watchdog, and disconnection of any of the cables to the measurement server will automatically disarm the robot and disable all program-controlled robot movements. Furthermore, the measurement server is equipped with two expansion slots which are reserved for future applications. Please note that the expansion slots do not have a standardized pinout and therefore only the expansion cards provided by SPEAG can be inserted. Expansion cards from any other supplier could seriously damage the measurement server. Calibration: No calibration required.

5.2 DATA ACQUISITION ELECTRONICS (DAE)

The data acquisition electronics (DAE3) consists of a highly sensitive electrometer grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD converter and a command decoder and control logic unit. Transmission to the measurement server is accomplished through an optical downlink for data and status information as well as an optical uplink for commands and the clock. The mechanical probe mounting device includes two different sensor systems for frontal and sideways probe contacts. They are used for mechanical surface detection and probe collision detection. The input impedance of the DAE3 box is 200MOhm; the inputs are symmetrical and floating. Common mode rejection is above 80 dB.



Figure 3: DAE

5.3 ER3DV6 ISOTROPIC E-FIELD PROBE FOR GENERAL NEAR-FILED MEASUREMENTS

Construction:	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether)
Calibration:	In air from 100 MHz to 3.0 GHz (absolute accuracy $\pm 6.0\%$, k=2)
Frequency:	100 MHz to > 6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity:	± 0.2 dB in air (rotation around probe axis)
	\pm 0.4 dB in air (rotation normal to probe axis)
Dynamic Range:	$2 \text{ V/m to} > 1000 \text{ V/m}$; Linearity: $\pm 0.2 \text{ dB}$
Dimensions:	Overall length: 330 mm (Tip: 16 mm)
	Tip diameter: 8 mm (Body: 12 mm)
Application:	Distance from probe tip to dipole centers: 2.5 mm The closest part of the sensor element is 1.1 mm closer to the tip General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

Figure 4 and 5: ER3DV6 E-Field Probe

5.4 H3DV6 ISOTROPIC E-FIELD PROBE FOR GENERAL NEAR-FILED **MEASUREMENTS Construction:** Three concentric loop sensors with 3.8 mm loop diameters resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material (resistant to organic solvents, e.g., glycolether) **Frequency:** 200 MHz to 3 GHz (absolute accuracy \pm 6.0%, k=2); Output linearized \pm 0.25 dB (spherical isotropy error) **Directivity:** Dynamic Range: 10 mA/m to 2 A/m at 1 GHz **E-Field Interference:** < 10% at 3 GHz (for plane wave) Overall length: 330 mm (Tip: 40 mm) **Dimensions:** Tip diameter: 6 mm (Body: 12 mm) Distance from probe tip to dipole centers: 3 mm The closest part of the sensor element is 1.9 mm closer to the tip **Application:** General magnetic near-field measurements up to 3 GHz Field component measurements Surface current measurements Measurements in air or liquids Low interaction with the measured field

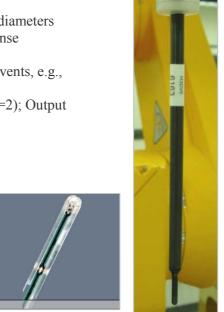


Figure 6 and 7: H3DV6 H-Field Probe

5.5 LIGHT BEAM UNIT

The light beam switch allows automatic "tooling" of the probe. During the process, the actual position of the probe tip with respect to the robot arm is measured, as well as the probe length and the horizontal probe offset. The software then corrects all movements, so that the robot coordinates are valid for the probe tip. The repeatability of this process is better than 0.1 mm. If a position has been taught with an aligned probe, the same position will be reached with another aligned probe within 0.1 mm, even if the other probe has different dimensions. During probe rotations, the probe tip will keep its actual position.



Figure 8: Light Beam Unit

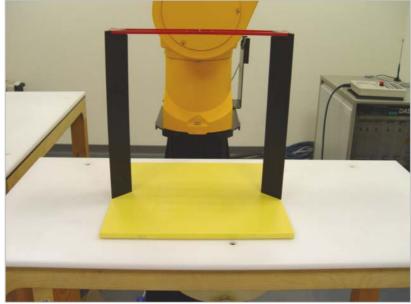
Dimensions:

Construction:

5.6 TEST ARCH

370 x 370 x 370mm

robot.



Enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the

Figure 9: Test Arch



5.7 PHONE POSITIONER

Construction:

Supports accurate and reliable positioning of any phone effect on near field <+/- 0.5dB



Figure 10: Phone positioner

5.8 SYSTEM VALIDATION KITS

Construction: Symmetrical dipole with built-in two step matching network and balun **CD835V3**

CD835V3	
Frequency Band:	800 - 960 MHz (free space)
Return Loss:	> 15 dB
Calibrated at:	835MHz
Power Capability:	50W continuous
Length & Height:	166 x 330 mm
CD1880V3	1.40
Frequency Band:	1710 - 2000 MHz (free space)
Return Loss:	> 18 dB
Calibrated at:	1880MHz
Power Capability:	50W continuous
Length & Height:	80.8 x 330 mm
CD2450V3	Fig
Frequency Band:	2250 - 2650 MHz (free space)
Return Loss:	> 18 dB over frequency band in free space
Calibrated at:	2450MHz
Power Capability:	50W continuous
Length & Height:	59.9 x 330 mm
Dipole Holder:	Tripod holder with adapter
Regular:	Hight Range 205 - 300 mm
Shortened:	Hight Range 160 - 210 mm

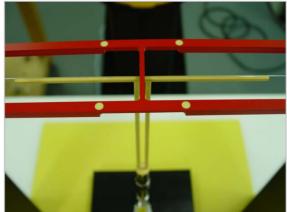


Figure 10: Dipole with Test Arch

5.9 SOFTWARE HAC V4.5

Easy teaching of predefined ANSI C63.19 measurement area Evaluation incorporates automatic exclusion of high-level areas Documentation ready for inclusion into compliance report.

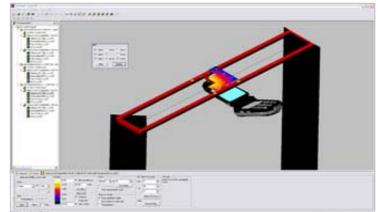


Figure 11: DASY4 software

6. EVALUATION PROCEDURES

DATA EVALUATION

The DASY4 post processing software (SEMCAD) automatically executes the following procedures to calculate the field units from the microvolt readings at the probe connector. The parameters used in the evaluation are stored in the configuration modules of the software:

Probe parameters:	- Sensitivity	<i>Norm</i> _{<i>i</i>} , a_{i0} , a_{i1} , a_{i2}
	- Conversion factor	$ConvF_i$
	- Diode compression point	dcp_i
Device parameters:	- Frequency	f
	- Crest factor	cf
Media parameters:	- Conductivity	σ
	- Density	ρ

These parameters must be set correctly in the software. They can be found in the component documents or be imported into the software from the configuration files issued for the DASY components. In the direct measuring mode of the multi-meter option, the parameters of the actual system setup are used. In the scan visualization and export modes, the parameters stored in the corresponding document files are used.

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$V_{i} = U_{i} + U_{i}^{2} \cdot \frac{cf}{dcp_{i}}$$

with V_{i} = Compensated signal of channel i (i = x, y, z)
 U_{i} = Input signal of channel i (i = x, y, z)
 cf = Crest factor of exciting field (DASY parameter)
 dcp_{i} = Diode compression point (DASY parameter)

From the compensated input signals the primary field data for each channel can be evaluated:

E-field probes:
$$E_i = \sqrt{\frac{V_i}{Norm_i \bullet ConvF}}$$

H-field probes:

$$H_{i} = \sqrt{Vi} \cdot \frac{a_{i10} + a_{i11}f + a_{i12}f^{2}}{f}$$

with V_i = Compensated signal of channel i (i = x, y, z) $Norm_i$ = Sensor sensitivity of channel i (i = x, y, z) $\mu V/(V/m)^2$ for E0field Probes

ConvF = Sensitivity enhancement in solution

aij = Sensor sensitivity factors for H-field probes

f = Carrier frequency (GHz)

Ei = Electric field strength of channel i in V/m

Hi = Magnetic field strength of channel i in A/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

$$SAR = E_{tot}^2 \cdot \frac{\sigma}{\rho \cdot 1000}$$

with SAR = local specific absorption rate in mW/g

$$E_{tot}$$
 = total field strength in V/m

 σ = conductivity in [mho/m] or [Siemens/m]

 ρ = equivalent tissue density in g/cm³

Note that the density is normally set to 1 (or 1.06), to account for actual brain density rather than the density of the simulation liquid.

The power flow density is calculated assuming the excitation field as a free space field.

$$P_{pwe} = \frac{E_{tot}^2}{3770}$$
 or $P_{pwe} = H_{tot}^2 \cdot 37.7$

with P_{pwe} = Equivalent power density of a plane wave in mW/cm²

 E_{tot} = total electric field strength in V/m

 H_{tot} = total magnetic field strength in A/m

7. MEASUREMENT UNCERTAINTY

Error DescriptionUncertainty ValueProbability distributionDivisor0Measurement System \pm \pm \pm \pm \pm Probe calibration \pm 5.1%Normal11Axial isotropy \pm 4.7%Rectangular $\sqrt{3}$ 1Sensor Displacement \pm 16.5%Rectangular $\sqrt{3}$ 1Boundary Effects \pm 2.4%Rectangular $\sqrt{3}$ 1Linearity \pm 4.7%Rectangular $\sqrt{3}$ 1Scaling to Peak Envelope Power \pm 2.0%Rectangular $\sqrt{3}$ 1Readout Electronics \pm 0.3%Rectangular $\sqrt{3}$ 1Response Time \pm 2.6%Rectangular $\sqrt{3}$ 1Integration Time \pm 2.6%Rectangular $\sqrt{3}$ 1RF Ambient Condition \pm 3.0%Rectangular $\sqrt{3}$ 1Probe Positioner \pm 1.2%Rectangular $\sqrt{3}$ 1Probe Positioning \pm 4.7%Rectangular $\sqrt{3}$ 1Probe Positioning \pm 4.7%Rectangular $\sqrt{3}$ 1Device Positioning Vertical \pm 4.7%Rectangular $\sqrt{3}$ 1Device Positioning Vertical \pm 4.7%Rectangular $\sqrt{3}$ 1Device Positioning Lateral \pm 1.0%Rectangular $\sqrt{3}$ 1Device Positioning Lateral \pm 1.0%Rectangular $\sqrt{3}$ 1Device Positioning Lateral \pm 1.0%Rectangular $\sqrt{3}$ 1Device Holder and Phantom \pm	(\mathbf{C}_i) (\mathbf{C}_i)) Std. Unc.	. Std. Unc.
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Readout Electronics $\pm 0.3\%$ Rectangular $\sqrt{3}$ 1Response Time $\pm 0.8\%$ Rectangular $\sqrt{3}$ 1Integration Time $\pm 2.6\%$ Rectangular $\sqrt{3}$ 1RF Ambient Condition $\pm 3.0\%$ Rectangular $\sqrt{3}$ 1RF Ambient Condition $\pm 12.0\%$ Rectangular $\sqrt{3}$ 1RF Reflections $\pm 12.0\%$ Rectangular $\sqrt{3}$ 1Probe Positioner $\pm 1.2\%$ Rectangular $\sqrt{3}$ 1Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Prover Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related </td <td>1</td> <td>±1.2%</td> <td>±1.2%</td>	1	±1.2%	±1.2%
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RF Ambient Condition $\pm 3.0\%$ Rectangular $\sqrt{3}$ 1RF Reflections $\pm 12.0\%$ Rectangular $\sqrt{3}$ 1Probe Positioner $\pm 1.2\%$ Rectangular $\sqrt{3}$ 1Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Test Sample Related 10% Rectangular $\sqrt{3}$ 1Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related 10% Rectangular $\sqrt{3}$ 1Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	1	±0.5%	±0.5%
RF Reflections $\pm 12.0\%$ Rectangular $\sqrt{3}$ 1Probe Positioner $\pm 1.2\%$ Rectangular $\sqrt{3}$ 1Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Test Sample Related \square \square \square Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related \square \square \square Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	1	±1.5%	±1.5%
Probe Positioner $\pm 1.2\%$ Rectangular $\sqrt{3}$ 1Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Test Sample Related \square \square \square Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related \square \square \square \square Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	1	±1.7%	±1.7%
Probe Positioning $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Test Sample Related $= 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related $= 42.4\%$ Rectangular $\sqrt{3}$ 1	1	±6.9%	±6.9%
Extrap. And Interpolation $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Test Sample Related \blacksquare \blacksquare Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related \blacksquare \blacksquare \blacksquare Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	0.67	±0.7%	±0.5%
Image: Point of the sector	0.67	±2.7%	±1.8%
Device Positioning Vertical $\pm 4.7\%$ Rectangular $\sqrt{3}$ 1Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related </td <td>1</td> <td>±0.6%</td> <td>±0.6%</td>	1	±0.6%	±0.6%
Device Positioning Lateral $\pm 1.0\%$ Rectangular $\sqrt{3}$ 1Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup RelatedPhantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1			
Device Holder and Phantom $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related 42.4% Rectangular $\sqrt{3}$ 1Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	0.67	±2.7%	±1.8%
Power Drift $\pm 5.0\%$ Rectangular $\sqrt{3}$ 1Phantom and Setup Related $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	1	±0.6%	±0.6%
Phantom and Setup Related \bigcirc Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$	1	±1.4%	±1.4%
Phantom Thickness $\pm 2.4\%$ Rectangular $\sqrt{3}$ 1	1	±2.9%	±2.9%
Combined Std. Uncertainty	0.67	±1.4%	±0.9%
		±14.7%	±10.9%
Expanded Std. Uncertainty on Power		±29.4%	±21.8%
Expanded Std. Uncertainty on Field		±14.7%	±10.9%

Table: Worst-case uncertainty budget for HAC free field assessment according to ANSI C63.19 [1]. The budget is valid for the frequency range 800 MHz – 3GHz and represents a worst-case analysis. For specific tests and configurations, the uncertainty could be considerably smaller.



8. TEST PROCEDURES

The following are RF emission step-by-step test procedures:

Test Instructions

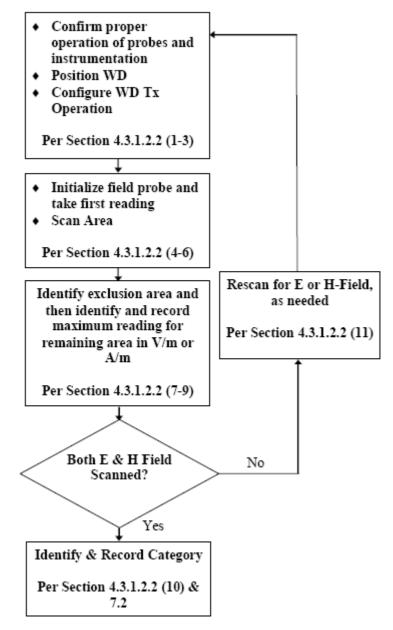


Figure 12: Near-field emission automated test flowchart



RF EMISSION TEST SETUP:

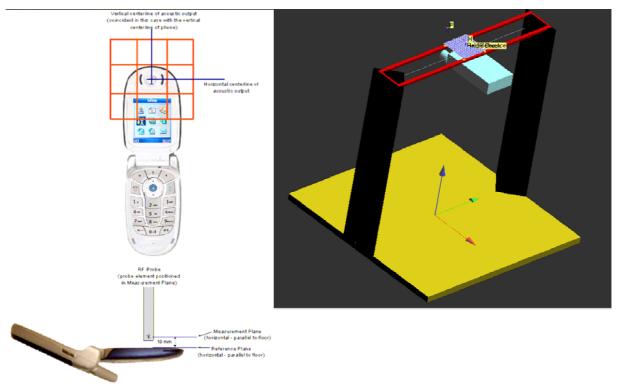


Figure 13: WD near-field emission test setup Figure 14: HAC test arch with WD setup

The following are measurement RF near field emission:

- 1. Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2. Position the WD in its intended test position. The WD's acoustic output point perpendicular to the field probe with test arch (sees the figure 13 and figure 14).
- 3. Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters, (e.g. test mode) as intended for the test. The fully charge battery was used for each test.
- 4. The center sub-grid was centered on the center of the WD output (acoustic or T-Coil output), as appropriate. The field probe at the initial test position in the 5 x 5 cm grid with a 5mm step size.
- 5. The field probe was aligned in the light beam. The phantom adjustment and verification procedure (1. surface check; 2. Verify Height 0.5mm above Center; 3. Verify Height 0.5mm above Center; 4 Verify Height for Scan) was performed before each setup change.
- 6. The measurement system was tested 5 x 5 cm grid with a 5mm step size. The probe was rotated 360° about the azimuth axis at the maximum interpolated position. The reading was recorded at each measurement procedure.
- 7. The power drift was measurement for each test. Power drift shall be below 5% or 0.25dB.If the power drift was higher than 5% or 0.25dB, the measurement was re-test.
- 8. Around the center sub-grid, five contiguous sub-grids around the center sub-grid with lowest maximum field strength reading. A maximum of five blocks can be excluded for both E- and H-field measurements for the WD output was measured.
- 9. The highest field strength reading was converted to peak V/m or A/m, as appropriate. This conversion was done using the appropriate probe modulation factor.
- 10. Repeat steps 1-9 for both the E- and H-field measurements.
- 11. The peak reading was according to the categories define in the C63.19 using the appropriate AWF.
- 12. The DASY4 software will control the DASY4 system to carried out the follow procedure for each mode testing.



9. PERFORMANCE

9.1 ARTICULATION WEIGHTING FACTOR (AWF)

The following AWF factors shall be used for the standard transmission protocols:

Standard	Technology	AWF (dB)
TIA/EIA/IS-2000	CDMA	0
TIA/EIA-136	TDMA (50 Hz)	0
J-STD-007	GSM (217)	-5
T1/T1P1/3GPP	UMTS (WCDMA)	0
iDENTM	TDMA (22 and 11 Hz)	0

Table 8.1 Articulation Weighting Factor (AWF)

9.2 TELEPHONE N-FILED CATEGORY

The following was shows the M-rating for wireless telephone:

Category	Telephone RF Parameters < 960 MHz				
Near Field	AWF	E-Field Emissions		H-Field Emissions	
Category M1/T1	0	56 to 61	dB (V/m)	+5.6 to +10.6	dB (A/m)
	-5	53.5 to 58.5	dB (V/m)	+3.1 to +8.1	dB (A/m)
Category M2/T2	0	51 to 56	dB (V/m)	+0.6 to +5.6	dB (A/m)
	-5	48.5 to 53.5	dB (V/m)	-1.9 to +3.1	dB (A/m)
Category M3/T3	0	46 to 51	dB (V/m)	-4.4 to +0.6	dB (A/m)
	-5	43.5 to 48.5	dB (V/m)	-6.9 to -1.9	dB (A/m)
Category M4/T4	0	< 46	dB (V/m)	< -4.4	dB (A/m)
	-5	< 43.5	dB (V/m)	< -6.9	dB (A/m)

Category	Telephone RF Parameters > 960 MHz				
Near Field	AWF	E-Field Emissions		H-Field Emissions	
Category M1/T1	0	46 to 51	dB (V/m)	-4.4 to 0.6	dB (A/m)
	-5	43.5 to 48.5	dB (V/m)	-6.9 to -1.9	dB (A/m)
Category M2/T2	0	41 to 46	dB (V/m)	-9.4 to -4.4	dB (A/m)
	-5	38.5 to 43.5	dB (V/m)	-11.9 to -6.9	dB (A/m)
Category M3/T3	0	36 to 41	dB (V/m)	-14.4 to -9.4	dB (A/m)
	-5	33.5 to 38.5	dB (V/m)	-16.9 to -11.9	dB (A/m)
Category M4/T4	0	<36	dB (V/m)	<-14.4	dB (A/m)
	-5	<33.5	dB (V/m)	<-16.9	dB (A/m)

 Table 8.2 Telephone near-field categories in linear units

NOTE	
The WD must be performed in the category M3	

10.MEASUREMENT RESULTS

10.1 SYSTEM CHECK

The test setup should be validated when first configured and verified periodically thereafter to ensure proper function. The procedure consists of two parts: dipole validation and determination of probe modulation factor.

10.2 DIPOLE VALIDATION

The HAC validation dipole antenna serves as a known source for an electrical and magnetic RF output. Figure 2 shows the setup used for the dipole validation.

1. The dipole antenna was placed in the position normally occupied by the WD.

2. The dipole was energized with a 20 dBm un-modulated continuous-wave signal.

3. The length of the dipole was scanned with both E-field and H-field probes and the maximum value for each scan was recorded.

4. The readings were compared with the values provided by the probe manufacturer and were found to agree within the allowed tolerance of 10%. Figure 2: Dipole Validation Procedure

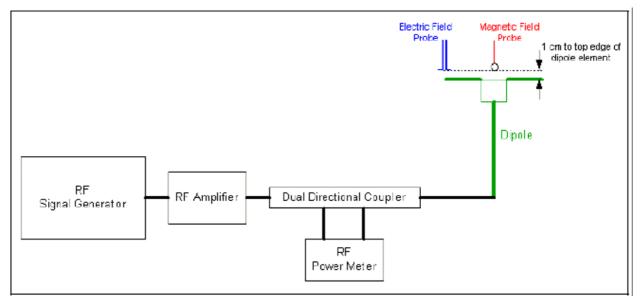


Figure 15: WD dipole calibration procedure

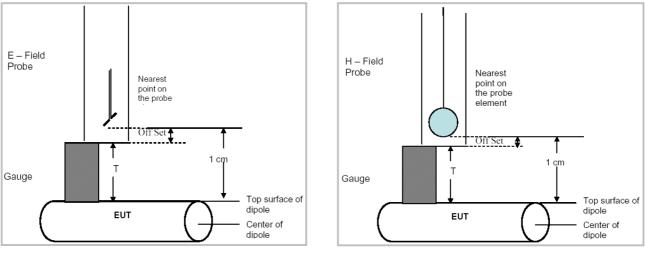


Figure 16

Figure 17

The probe is positioned over the illuminated dipole at 10 mm distance from the nearest point on the probe sensor element to the top surface (edge) of the dipole element.



9.1.1 Probe Modulation Factor

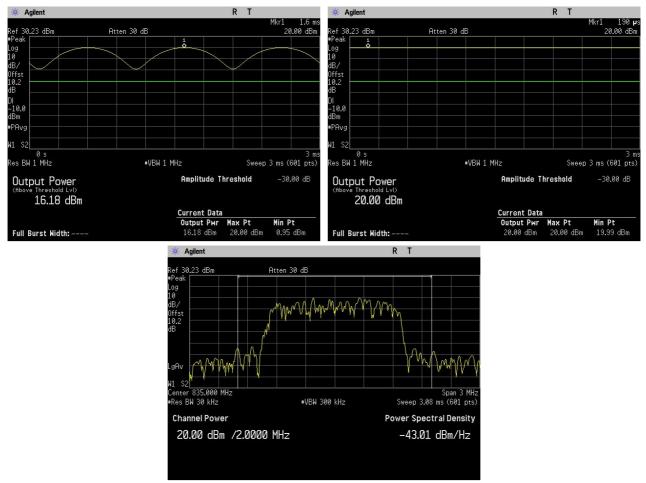
In addition, a calibration shall be made of the modulation response of the probe and its instrumentation chain. This calibration shall be performed with the field probe, attached to the instrumentation that is to be used with it during the measurement. The response of the probe system to a CW field at the frequency(s) of interest is compared to its response to a modulated signal with equal peak amplitude. The field level of the test signals shall be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated field shall be applied to the readings taken of modulated fields of the specified type. This was done using the following procedure:

1. Fixing the probe in a set location relative to a field generating device, such as a reference dipole antenna, as illustrated in Figure 15.

- 2. Illuminate the probe with a CW signal at the intended measurement frequency.
- 3. Record the reading of the probe measurement system of the CW signal.
- 4. Determine the level of the CW signal being used to drive the field generating device.
- 5. Substitute a signal using the same modulation as that used by the intended WD for the CW signal.
- 6. Set the amplitude during transmission of the modulated signal to equal the amplitude of the CW signal.
- 7. Record the reading of the probe measurement system of the modulated signal.
- 8. The ratio of the CW to modulated signal reading is the modulation factor

9.1.2 Measurement Power

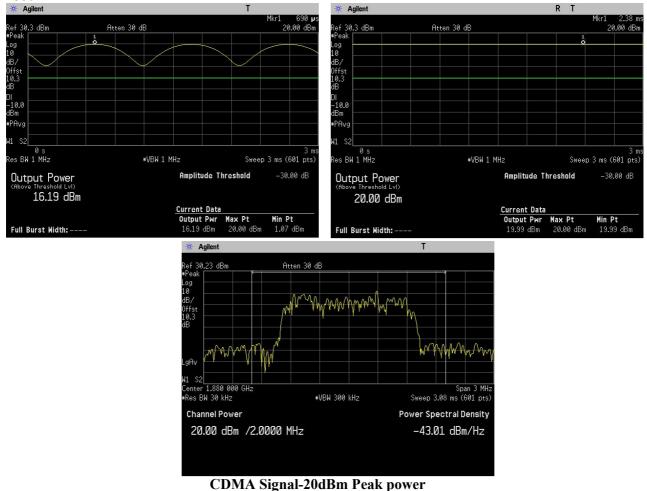
835MHz

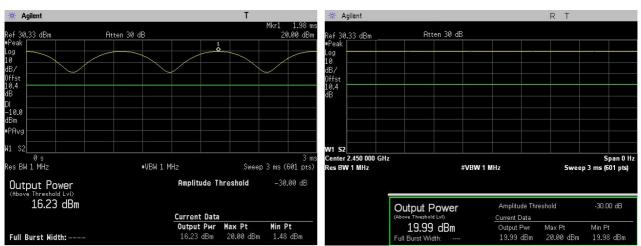


CDMA Signal-20dBm Peak power



1880MHz





2450MHz:

20dBm Peak power

f(MHz)	Signal Type	Pulse Average Power (dBm)	Measurement H-field (A/m)	Target E-Field (V/m)	Deviation %	Mod. Factor Ration
835.00	CW	20.00	156.20	162.50	-3.88	-
835.00	AM80%	20.00	98.20	_	—	1.59
835.00	CDMA	20.00	148.20	-	-	1.05
1880.00	CW	20.00	134.50	138.50	-2.89	_
1880.00	AM80%	20.00	83.60	_	_	1.61
1880.00	CDMA	20.00	127.20	_	_	1.06
2450.00	CW	20.00	131.80	131.80	0.00	_
2450.00	AM80%	20.00	75.20	-	_	1.75
f(MHz)	Signal Type	Pulse Average Power (dBm)	Measurement H-field (A/m)	Target E-Field (V/m)	Deviation %	Mod. Factor Ration
f(MHz) 835.00	0	Average Power	H-field	0		Factor
· · ·	Туре	Average Power (dBm)	H-field (A/m)	E-Field (V/m)	%	Factor
835.00	Type CW	Average Power (dBm) 20.00	H-field (A/m) 0.445	E-Field (V/m)	%	Factor Ration
835.00 835.00	Type CW AM80%	Average Power (dBm) 20.00 20.00	H-field (A/m) 0.445 0.286	E-Field (V/m)	%	Factor Ration - 1.56
835.00 835.00 835.00	Type CW AM80% CDMA	Average Power (dBm) 20.00 20.00 20.00	H-field (A/m) 0.445 0.286 0.428	E-Field (V/m) 0.451 – –	% -1.33 − −	Factor Ration - 1.56
835.00 835.00 835.00 1880.00	Type CW AM80% CDMA CW	Average Power (dBm) 20.00 20.00 20.00 20.00	H-field (A/m) 0.445 0.286 0.428 0.450	E-Field (V/m) 0.451 – –	% -1.33 − −	Factor Ration - 1.56 1.04
835.00 835.00 835.00 1880.00 1880.00	Type CW AM80% CDMA CW AM80%	Average Power (dBm) 20.00 20.00 20.00 20.00 20.00	H-field (A/m) 0.445 0.286 0.428 0.450 0.288	E-Field (V/m) 0.451 – –	% -1.33 − −	Factor Ration - 1.56 1.04 - 1.56

9.1.3 Validation and Modulation Factor

Note:

1. Modulation Factor =Measured E/H Field (CW)/Measured E/H Field (Modulation)

2. The HAC measurement of peak V/m or A/m should be calculation by formula or insert crest factor in the day4 software.

3. Peak(dB V/m or dB A/m)=20 x log(Reading[time averaging V/m or A/m] x Probe Modulation Factor)



10.3 EUT TUNE-UP PROCEDURES

The following procedures had been used to prepare the EUT for the SAR test.

• To setup the desire channel frequency and the maximum output power. A Radio Communication Tester "Agilent, model: E5515C (8960 SERIES 10)" was used to program the EUT.

Operation Mode: Active Cell

System Mode: IS-2000

Call Parms	Cell	band
Call Farms	US Cellular	US PCS
Channel	1013 / 384 / 777	25 / 600 / 1175
Protocol Rev	6 (IS-2000-0)	6 (IS-2000-0)
Radio Config	(Fwd3, Rvs3), S055 (Loopback)	(Fwd3, Rvs3), S055 (Loopback)
Rvs Power Ctrl	All Up Bits	All Up Bits
Power Ctrl Size	1.0 dBm	1.0 dBm
Call Drop Timer	Off	Off
Call Limit Mode	Off	Off
Traffic Dada Rate	Full	Full
Rcvr Power Ctrl	Manual	Manual
Meas Frequency	Auto	Auto
Voice SO Mode	Voice Echo	Voice Echo
Echo Delay	Medium	Medium

Measurement Conducted output power(dBm):

		Channel	1013(cell	ular band)	600(PCS band)		
Test Mo	de		Peak	Averag	e	Peak	Average	
(Fwd5,	Rvs4),SO	55(Loopback)	25.69	23.37		26.77	24.34	
(Fwd4,	Rvs3),SO	55(Loopback)	25.66	23.38		26.79	24.32	
(Fwd3,	Rvs3),SO	55(Loopback)	25.71	23.39		26.86	24.27	
(Fwd2,	Rvs2),SO	55(Loopback)	25.68	23.35		26.80	24.35	
(Fwd1,	Rvs1),SO	55(Loopback)	25.65	23.35		26.79	24.30	
(Fwd5	,Rvs4),SO	9(Loopback)	25.67	23.33		26.83	24.31	
(Fwd4	,Rvs3),SO	2(Loopback)	25.68	23.36		26.79	24.33	
(Fwd3	,Rvs3),SO	2(Loopback)	25.69	24.34		26.84	24.36	
(Fwd2	,Rvs2),SO	9(Loopback)	25.69	23.36		26.82	24.31	
(Fwd1	,Rvs1),SO	2(Loopback)	25.67	23.36		26.83	24.26	
Channel	f(MHz)	Average Power(e	d <u>Bm)</u>	Channel	f(MI	<u>Hz)</u> Aver	age Power(dBm)	
1013	824.70	25.08		25	1851.	.25 24.8	7	
384	836.52	24.34		600	1880.	00 25.0	8	
777	848.31	24.92		1175	1908.	.75 24.7	4	

The following procedures has been used to prepare the Bluetooh for the HAC collocation test.

• The client supplied a special driving program to control the EUT to continually transmit the specified maximum power

Bluetooth:Measurement Conducted output power:Channelf(MHz)Power(dBm)(peak)02402-0.60392441-0.10782480-0.26

• Maximum conducted power was measured by replacing the antenna with an adapter for conductive measurements, before and after the SAR measurements was done.

10.4HAC MEASUREMENT RESULTS

1. E-Field Emission (Close slide cover mode):

Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	93.9	39.45	0.134	39.59	51	-11.41	M4
CDMA	384	Fixed	ON	100.8	40.07	0.016	40.09	51	-10.91	M4
CDMA	777	Fixed	ON	91.3	39.21	0.093	39.30	51	-11.70	M4
DMA C	ellular Ban	d with Blu	ietooth(co-L	ocation to						
Mode	Channel	Antenna	Backlight	Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	91.8	39.26	0.034	39.29	51	-11.71	M4
CDMA	384	Fixed	ON	100.0	40.00	0.054	40.05	51	-10.95	M4
CDMA	777	Fixed	ON	91.9	39.27	0.029	39.30	51	-11.70	M4
Mode	CS Band Channel	Duty cycle Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	63.3	36.03	0.046	36.07	41	-4.93	M3
CDMA	600	Fixed	ON	67.7	36.61	0.012	36.62	41	-4.38	M3
CDMA	1175	Fixed	ON	64.4	36.18	0.010	36.19	41	-4.81	M3
DMA P	CS Band v	vith Blueto	oth(co-Loca	tion test)	Duty cycle	e:100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	60.8	35.68	0.011	35.69	41	-5.31	M4
CDMA	600	Fixed	ON	65.2	36.28	0.079	36.36	41	-4.64	M3
CDMA	1175	Fixed	ON	61.9	35.83	0.036	35.87	41	-5.13	M4

2. E-Field Emission(Open slide cover mode):

Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	91.8	39.26	0.020	39.28	51	-11.72	M4
CDMA	384	Fixed	ON	93.3	39.40	0.047	39.44	51	-11.56	M4
CDMA	777	Fixed	ON	90.0	39.08	0.017	39.10	51	-11.90	M4
CDMA C	ellular Ban	d with Blu	etooth(coloo	cation tes	t) Duty cy	cle:100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	90.7	39.15	0.066	39.22	51	-11.78	M4
CDMA	384	Fixed	ON	92.5	39.32	0.032	39.35	51	-11.65	M4
CDMA	777	Fixed	ON	88.7	38.96	0.017	38.98	51	-12.02	M4
CDMA P	CS Band	Duty cycle	e:100%							
Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	79.8	38.04	0.021	38.06	41	-2.94	M3
CDMA	600	Fixed	ON	85.6	38.65	0.025	38.67	41	-2.33	M3
CDMA	1175	Fixed	ON	83.6	38.44	0.049	38.49	41	-2.51	M3
CDMA P	CS Band v	vith Blueto	oth(colocati	on test) D	uty cycle:	100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (V/m)	Peak Filed (dB V/m)	Power drift (dB)	Extrapolate Field (dB V/m)	Limit (dB V/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	77.7	37.81	0.021	37.83	41	-3.17	M3
CDMA	600	Fixed	ON	84.5	38.54	0.012	38.55	41	-2.45	M3
CDMA	1175	Fixed	ON	81.0	38.17	0.009	38.18	41	-2.82	M3
	00 D 1 T		Outy cycle:10	000/						

3. H-Field Emissions (Close slide cover mode):

Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	0.312	-10.12	0.091	-10.03	0.6	-10.63	M4
CDMA	384	Fixed	ON	0.319	-9.92	0.025	-9.90	0.6	-10.50	M4
CDMA	777	Fixed	ON	0.297	-10.54	0.061	-10.48	0.6	-11.08	M4
CDMA C	ellular Ban	d with Blu	etooth(co-L	ocation te	st) Duty c	ycle:100%	6			
Mode	Channel	Antenna	Backlight	Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	ON	0.302	-10.40	0.091	-10.31	0.6	-10.91	M4
CDMA	384	Fixed	ON	0.324	-9.79	0.023	-9.77	0.6	-10.37	M4
CDMA	777	Fixed	ON	0.301	-10.43	0.058	-10.37	0.6	-10.97	M4
Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	0.261	-11.67	0.053	-11.61	-9.4	-2.21	M3
CDMA	600	Fixed	ON	0.279	-11.09	0.044	-11.04	-9.4	-1.64	M3
CDMA	1175	Fixed	ON	0.262	-11.63	0.051	-11.58	-9.4	-2.18	M3
CDMA P	CS Band v	vith Blueto	oth(co-Loca		Duty cycle	e:100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	ON	0.255	-11.87	0.055	-11.81	-9.4	-2.41	M3
CDMA	600	Fixed	ON	0.277	-11.15	0.053	-11.10	-9.4	-1.70	M3
CDMA	1175	Fixed	ON	0.259	-11.73	0.030	-11.70	-9.4	-2.30	M3

4. H-Field Emissions (Open slide cover mode):

Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	OFF	0.290	-10.75	0.053	-10.70	0.6	-11.30	M4
CDMA	384	Fixed	OFF	0.297	-10.54	0.044	-10.50	0.6	-11.10	M4
CDMA	777	Fixed	OFF	0.285	-10.90	0.051	-10.85	0.6	-11.45	M4
CDMA C	ellular Ban	d with Blue	etooth(coloc	ation test) Duty cyc	le:100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	1013	Fixed	OFF	0.290	-10.75	0.055	-10.70	0.6	-11.30	M4
CDMA	384	Fixed	OFF	0.296	-10.57	0.053	-10.52	0.6	-11.12	M4
CDMA	777	Fixed	OFF	0.282	-11.00	0.030	-10.97	0.6	-11.57	M4
Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	OFF	0.257	-11.80	0.016	-11.79	-9.4	-2.39	M3
CDMA	600	Fixed	OFF	0.280	-11.06	0.046	-11.01	-9.4	-1.61	M3
CDMA	1175	Fixed	OFF	0.272	-11.31	0.061	-11.25	-9.4	-1.85	M3
CDMA P	CS Band v	vith Blueto	oth(colocatio		uty cycle:	100%				
Mode	Channel	Antenna	Backlight	Time Avg. Field (A/m)	Peak Filed (dB A/m)	Power drift (dB)	Extrapolate Field (dB A/m)	Limit (dB A/m)	Margin (dB)	M-Rating Category Result
CDMA	25	Fixed	OFF	0.250	-12.04	0.031	-12.01	-9.4	-2.61	M3
CDMA	600	Fixed	OFF	0.278	-11.12	0.023	-11.10	-9.4	-1.70	M3
CDMA	1175	Fixed	OFF	0.269	-11.40	0.060	-11.34	-9.4	-1.94	M3

11.EQUIPMENT LIST & CALIBRATION STATUS

Name of Equipment	Manufacturer	Type/Model	Serial Number	Calibration Cycle(days)	Calibration Due
Power Meter	Agilent	E4416A	GB41291611	365	05/24/07
Power Sensor	Agilent	E9327A	US40441097	365	05/24/07
Thermometer	Amarell	4046	25060	3650	10/02/14
Thermometer	Amarell	4046	25058	3650	10/02/14
Wireless Communication Test Set	Agilent	E5515C	GB44051665	365	06/14/07
Signal Generator	Agilent	E8257C	US42340383	365	06/26/07
Spectrum Analyzer	Agilent	E4446A	US42510252	365	08/02/07
Amplifier	Mini-Circuit	ZVE-8G	N/A	N/A	N/A
Amplifier	Mini-Circuit	ZHL-1724HLN	N/A	N/A	N/A
DC Power generator	ABM	8301HD	N/A	N/A	N/A
Data Acquisition Electronics (DAE)	SPEAG	DAE3	500	365	08/23/07
E-Field Probe	SPEAG	ER3DV6	2345	365	05/30/07
H-Field Probe	SPEAG	H3DV6	6163	365	05/30/07
835 MHz System Validation Dipole	SPEAG	CD835V3	1031	730	04/26/07
1880 MHz System Validation Dipole	SPEAG	CD1880V3	1024	730	06/01/07
2450 MHz System Validation Dipole	SPEAG	CD2450V3	1026	730	04/28/07
Probe Alignment Unit	SPEAG	LB (V2)	348	N/A	N/A
Robot	Staubli	RX90B L	F02/5T69A1/A/01	N/A	N/A
HAC Test Arch	SPEAG	SD HAC P01 BA	1027	N/A	N/A
Devices Holder	SPEAG	N/A	N/A	N/A	N/A



12.LOCATION OF TEST SITE

All measurement facilities used to collect the measurement data are located at

- No. 81-1, Lane 210, Bade Rd. 2, Luchu Hsiang, Taoyuan Hsien, Taiwan, R.O.C.
- No. 11, Wu-Kung 6 Rd, Wu-Ku Hsiang, Wu-Ku Industrial District, Taipei Hsien, (248) Taiwan.
- No. 199, Chunghsen Road, Hsintien City, Taipei Hsien, Taiwan, R.O.C.

13.ATTACHMENTS

No.	Contents	No. of page (s)
1	System Check Plot	32
2	HAC Test Plot	96
3	Certificate of E-filed Probe ER3DV6 SN:2345	9
4	Certificate of H-filed Probe H3DV6 SN:6163	8
5	Certificate of System Validation Dipole CD835V3 SN:1031	6
6	Certificate of System Validation Dipole CD1880V3 SN:1024	6
7	Certificate of System Validation Dipole CD2450V3 SN:1026	6

END OF REPORT